

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1378 0	trench near5 (isolation or "field oxide" or LOCOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	1402 2	trench near5 (liner or line or conductive or metal or "tungsten silicide" or "titanium nitride" or "silicon nitride" or tungsten or polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	4579	1 and 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L4	4220	semiconductor and 3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	L5	3994	@ad<=20011012 and 4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L7	2029	257/\$ and 5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L9	1965	5 not 7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB